

**FDY6342L** 

## **Integrated Load Switch**

November 2014

#### **Features**

- Max  $r_{DS(on)} = 0.5 \Omega$  at  $V_{GS} = 4.5 \text{ V}$ ,  $I_D = -0.83 \text{ A}$
- Max  $r_{DS(on)} = 0.7 \Omega$  at  $V_{GS} = 2.5 \text{ V}$ ,  $I_D = -0.70 \text{ A}$
- Max  $r_{DS(on)} = 1.2 \Omega$  at  $V_{GS} = 1.8 \text{ V}$ ,  $I_D = -0.43 \text{ A}$
- Max  $r_{DS(on)} = 1.8 \Omega$  at  $V_{GS} = 1.5 \text{ V}$ ,  $I_D = -0.36 \text{ A}$
- Control MOSFET (Q1) includes Zener protection for ESD ruggedness (>4 kV Human body model)
- High performance trench technology for extremely low r<sub>DS(on)</sub>
- Compact industry standard SC89-6 surface mount package
- RoHS Compliant

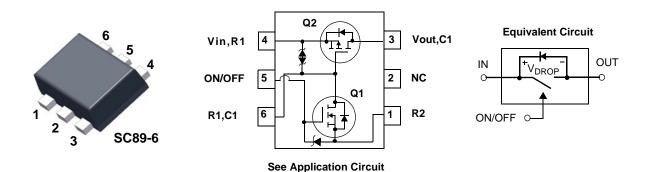


#### **General Description**

This device is particularly suited for compact power management in portable electronic equipment where 2.5 V to 8 V input and 0.83 A output current capability are needed. This load switch integrates a small N-Channel power MOSFET (Q1) that drives a large P-Channel power MOSFET (Q2) in one tiny SC89-6 package.

#### **Applications**

- Power management
- Load switch



### MOSFET Maximum Ratings T<sub>A</sub> = 25 °C unless otherwise noted

Symbol	Parameter	Ratings	Units		
V <sub>IN</sub>	Gate to Source Voltage (Q2)		±8	V	
V <sub>ON/OFF</sub>	Gate to Source Voltage (Q1)		-0.5 to 8	V	
I <sub>Load</sub>	Load Current -Continuous	(Note 2)	0.83	A	
	-Pulsed	(Note 2)	1.0		
Б	Power Dissipation	(Note 1a)	0.625	W	
$P_{D}$	Power Dissipation (Note 1b)		0.446	VV	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range		-55 to +150	°C	

#### **Thermal Characteristics**

$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1a)	200	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	(Note 1b)	280	*C/VV

#### **Package Marking and Ordering Information**

Device Marking Device		Package	Reel Size	Tape Width	Quantity	
Н	FDY6342L	SC89-6	7 "	8 mm	3000 units	

## **Electrical Characteristics** $T_J = 25$ °C unless otherwise noted **Parameter**

_						
Off Characteristics						
$BV_{IN}$	V <sub>IN</sub> Breakdown Voltage	$I_D = -250 \mu A, V_{ON/OFF} = 0 V$	8			V
I <sub>Load</sub>	Zero Gate Voltage Drain Current	$V_{IN} = -6.4 \text{ V}, V_{ON/OFF} = 0 \text{ V}$			-1	μΑ
I <sub>FL</sub>	Leakage Current, Forward	V <sub>IN</sub> = 8 V, V <sub>ON/OFF</sub> = 0 V			10	μΑ
$I_{RL}$	Leakage Current, Reverse	$V_{IN} = -8 \text{ V}, V_{ON/OFF} = 0 \text{ V}$			-10	μΑ

**Test Conditions** 

### On Characteristics (note 2)

Symbol

V <sub>ON/OFF(th)</sub>	Gate Threshold Voltage	$V_{IN} = V_{ON/OFF}$ , $I_D = -250 \mu A$	0.65	0.85	1.5	V
	Static Drain to Source On Resistance (Q2)	$V_{IN} = 4.5 \text{ V}, I_D = -0.83 \text{ A}$		0.28	0.5	Ω
		$V_{IN} = 2.5 \text{ V}, I_D = -0.70 \text{ A}$		0.35	0.7	
r <sub>DS(on)</sub>		$V_{IN} = 1.8 \text{ V}, I_D = -0.43 \text{ A}$		0.45	1.2	
		$V_{IN} = 1.5 \text{ V}, I_D = -0.36 \text{ A}$		0.57	1.8	
	Static Drain to Source On Resistance (Q1)	$V_{IN} = 4.5 \text{ V}, I_D = 0.4 \text{ A}$		2.9	4.0	
		$V_{IN} = 2.7 \text{ V}, I_D = 0.2 \text{ A}$		3.5	5.0	22

#### **Drain-Source Diode Characteristics**

Ī	s	Maximum Continuous Drain to Source Diode Forward Current			-0.25	Α
,	$V_{SD}$	Source to Drain Diode Forward Voltage	$V_{ON/OFF} = 0 \text{ V}, I_S = -0.25 \text{ A (Note 2)}$	-0.8	-1.2	V

1.  $R_{\theta JA}$  is determined with the device mounted on a 1 in<sup>2</sup> pad 2 oz copper pad on a 1.5 x 1.5 in. board of FR-4 material.  $R_{\theta JC}$  is guaranteed by design while  $R_{\theta JA}$  is determined by the user's board design.



a)200 °C/W when mounted on a 1 in² pad of 2 oz copper.



b)280 °C/W when mounted on a minimum pad of 2 oz copper.

Min

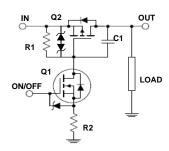
Тур

Max

Units

2. Pulse Test: Pulse Width < 300  $\mu$ s, Duty cycle < 2.0%.

### FDY6342L Load Switch Application circuit



#### **External Component Recommendation:**

For additional in-rush current control, R2 and C1 can be added. For more information, see application note AN1030

### Typical Characteristics T<sub>J</sub> = 25 °C unless otherwise noted

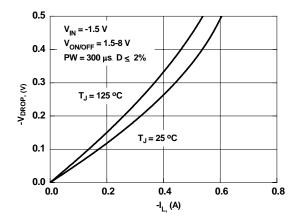


Figure 1. Conduction Voltage Drop Variation with Load Current

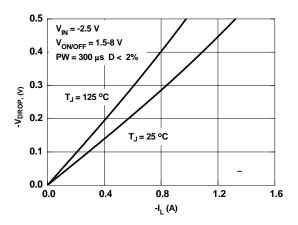


Figure 3. Conduction Voltage Drop Variation with Load Current

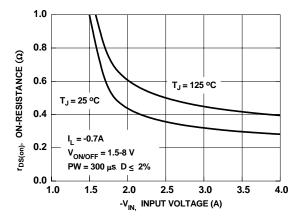


Figure 5. On-Resistance Variaton with Input Current

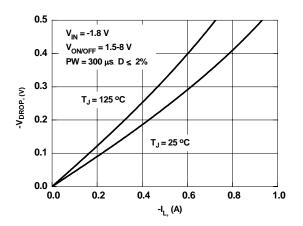


Figure 2. Conduction Voltage Drop Variation with Load Current

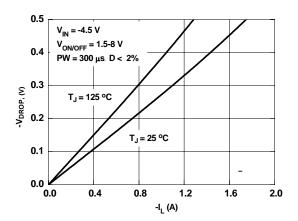


Figure 4. Conduction Voltage Drop Variation with Load Current

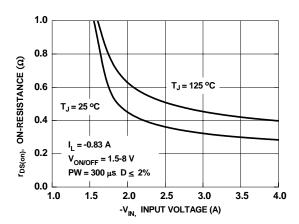
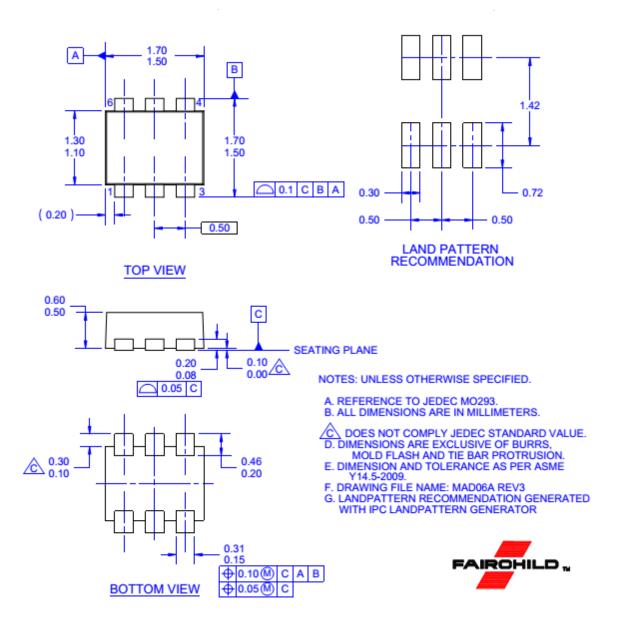


Figure 6. On-Resistance Variaton with Input Current

### **Dimensional Outline and Pad Layout**



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